74AHC74-Q100; 74AHCT74-Q100

Dual D-type flip-flop with set and reset; positive-edge triggerRev. 3 — 22 April 2020Product data sheet

1. General description

The 74AHC74-Q100; 74AHCT74-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-Power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7-A.

The 74AHC74-Q100; 74AHCT74-Q100 is a dual positive-edge triggered, D-type flip-flop with individual data inputs (D), clock inputs (CP), set inputs (SD) and reset inputs (\overline{RD}). It also has complementary outputs (Q and \overline{Q}).

The set and reset are asynchronous active LOW inputs that operate independent of the clock input. Information on the data input is transferred to the Q output on the LOW to HIGH transition of the clock pulse. The data inputs must be stable one set-up time prior to the LOW to HIGH clock transition for predictable operation.

Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

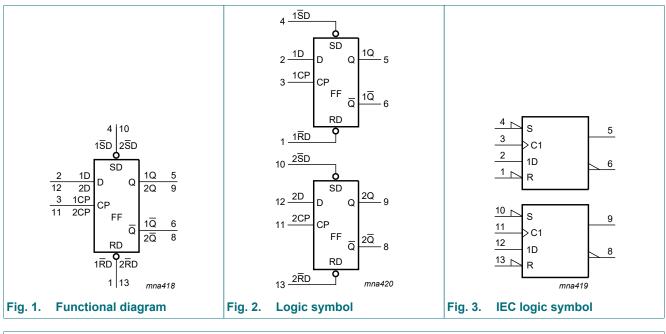
- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - For 74AHC74-Q100: CMOS level
 - For 74AHCT74-Q100: TTL level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

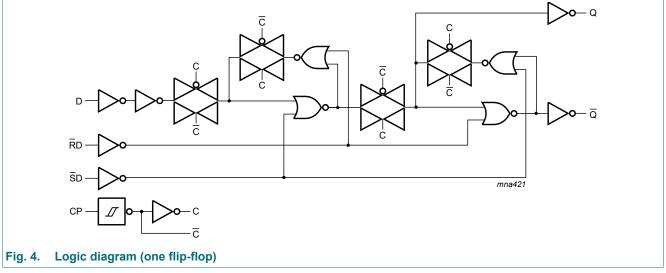
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3. Ordering information

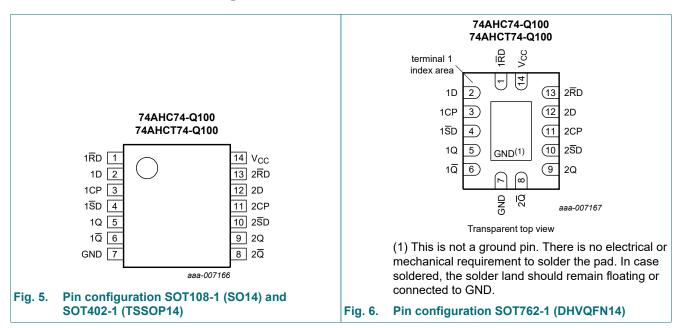
Type number	Package						
	Temperature range	Name	Description	Version			
74AHC74D-Q100	-40 °C to +125 °C	SO14	SO14 plastic small outline package; 14 leads; body width 3.9 mm				
74AHCT74D-Q100							
74AHC74PW-Q100	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads;	SOT402-1			
74AHCT74PW-Q100			body width 4.4 mm				
74AHC74BQ-Q100	-40 °C to +125 °C	DHVQFN14	DHVQFN14 plastic dual in-line compatible thermal				
74AHCT74BQ-Q100			enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm				

4. Functional diagram





5. Pinning information



5.1. Pinning

5.2. Pin description

Symbol	Pin	Description			
1RD	1	asynchronous reset direct input (active LOW)			
1D	2	data input			
1CP	3	clock input (LOW to HIGH, edge-triggered)			
1 S D	4	asynchronous set direct input (active LOW)			
1Q	5	true flip-flop output			
1 <u>Q</u>	6	complement flip-flop output			
GND	7	ground (0 V)			
2 <u>Q</u>	8	complement flip-flop output			
2Q	9	true flip-flop output			
2 S D	10	asynchronous set direct input (active LOW)			
2CP	11	clock input (LOW to HIGH, edge-triggered)			
2D	12	data input			
2RD	13	asynchronous reset direct input (active LOW)			
V _{CC}	14	supply voltage			

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care;

↑ = LOW to HIGH transition; Q_{n+1} = state after the next LOW to HIGH CP transition.

Control	Control			Output			
nSD	nRD	nCP	nD	nQ	nQ	nQ _{n+1}	nQn+1
L	Н	X	Х	Н	L	-	-
Н	L	X	Х	L	н	-	-
L	L	X	Х	Н	Н	-	-
Н	Н	1	L	-	-	L	Н
Н	Н	1	Н	-	-	Н	L

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V ₁ < -0.5 V [1]	-20	-	mA
I _{OK}	output clamping current	$V_{\rm O} < -0.5 \text{ V or } V_{\rm O} > V_{\rm CC} + 0.5 \text{ V}$ [1]	-20	+20	mA
lo	output current	$V_{\rm O}$ = -0.5 V to (V _{CC} + 0.5 V)	-25	+25	mA
I _{CC}	supply current		-	+75	mA
I _{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT108-1 (SO14) package: P_{tot} derates linearly with 10.1 mW/K above 100 °C. For SOT402-1 (TSSOP14) package: P_{tot} derates linearly with 7.3 mW/K above 81 °C. For SOT762-1 (DHVQFN14) package: P_{tot} derates linearly with 9.6 mW/K above 98 °C.

8. Recommended operating conditions

Table 5. Operating conditions

Symbol	Parameter	Conditions	Conditions 74AHC74-Q100				74AHCT74-Q100			
			Min	Тур	Мах	Min	Тур	Max		
V _{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V	
VI	input voltage		0	-	5.5	0	-	5.5	V	
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V	
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C	
Δt/ΔV	input transition rise and fall rate	V _{CC} = 3.0 V to 3.6 V	-	-	100	-	-	-	ns/V	
		V _{CC} = 4.5 V to 5.5 V	-	-	20	-	-	20	ns/V	

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-	°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	
74AHC7	4-Q100									
VIH	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
VIL	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -50 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -50 μA; V _{CC} = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I _O = -50 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
		I _O = -8.0 mA; V _{CC} = 4.5 V	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 50 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		I _O = 8.0 mA; V _{CC} = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
lı	input leakage current	V ₁ = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	2.0	-	20	-	40	μA
CI	input capacitance	V _I = V _{CC} or GND	-	3	10	-	10	-	10	pF
74AHCT	74-Q100				•					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -8.0 mA	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
lı	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	2.0	-	20	-	40	μA

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	
ΔI _{CC}	additional supply current	per input pin; V _I = V _{CC} - 2.1 V; other pins at V _{CC} or GND; $I_O = 0 A$; V _{CC} = 4.5 V to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
Cı	input capacitance	V _I = V _{CC} or GND	-	3	10	-	10	-	10	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 9.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Мах	Min	Max	Min	Max]
74AHC7	4-Q100									
t _{pd}		nCP to nQ, $n\overline{Q}$; see Fig. 7 [2]								
	delay	V_{CC} = 3.0 V to 3.6 V; C _L = 15 pF	-	5.2	11.9	1.0	14.0	1.0	15.0	ns
		V_{CC} = 3.0 V to 3.6 V; C _L = 50 pF	-	7.4	15.4	1.0	17.5	1.0	19.5	ns
		V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF	-	3.7	7.3	1.0	8.5	1.0	9.5	ns
		V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF	-	5.2	9.3	1.0	10.5	1.0	12.0	ns
		nSD, nRD to nQ, nQ; see <u>Fig. 8</u>								
		V_{CC} = 3.0 V to 3.6 V; C _L = 15 pF	-	5.4	12.3	1.0	14.5	1.0	15.5	ns
	V_{CC} = 3.0 V to 3.6 V; C _L = 50 pF	-	7.7	15.8	1.0	18.0	1.0	20.0	ns	
		V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF	-	3.7	7.7	1.0	9.0	1.0	10.0	ns
		V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF	-	5.3	9.7	1.0	11.0	1.0	12.5	ns
f _{max} maximum		see Fig. 7								
	frequency	V_{CC} = 3.0 V to 3.6 V; C _L = 15 pF	80	125	-	70	-	70	-	MHz
		V_{CC} = 3.0 V to 3.6 V; C _L = 50 pF	50	75	-	45	-	45	-	MHz
		V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF	130	170	-	110	-	110	-	MHz
		V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF	90	115	-	75	-	75	-	MHz
t _W	pulse width	CP HIGH or LOW; nSD, nRD LOW; see <u>Fig. 7</u> and <u>Fig. 8</u>								
		V _{CC} = 3.0 V to 3.6 V	6.0	-	-	7.0	-	7.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	nD to nCP; see <u>Fig. 7</u>								
		V _{CC} = 3.0 V to 3.6 V	6.0	-	-	7.0	-	7.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
t _h	hold time	nD to nCP; see <u>Fig. 7</u>								
		V _{CC} = 3.0 V to 3.6 V	0.5	-	-	0.5	-	0.5	-	ns
		V _{CC} = 4.5 V to 5.5 V	0.5	-	-	0.5	-	0.5	-	ns

74AHC74-Q100; 74AHCT74-Q100

Dual D-type flip-flop with set and reset; positive-edge trigger

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
t _{rec}	recovery	nRD to nCP; see <u>Fig. 8</u>								
	time	V _{CC} = 3.0 V to 3.6 V	5.0	-	-	5.0	-	5.0	-	ns
		V _{CC} = 4.5 V to 5.5 V	3.0	-	-	3.0	-	3.0	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_1 = \text{GND to } V_{\text{CC}}$ [5	3] -	12	-	-	-	-	-	pF
74AHCT	74-Q100		·							
t _{pd}		nCP to nQ, $n\overline{Q}$; see Fig. 7 [2	2]							
	delay	V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF	-	3.3	7.8	1.0	9.0	1.0	10.0	ns
		V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF	-	4.8	8.8	1.0	10.0	1.0	11.0	ns
		$n\overline{S}D$, $n\overline{R}D$ to nQ , $n\overline{Q}$; see <u>Fig. 8</u>								
		V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF	-	3.7	10.4	1.0	12.0	1.0	13.0	ns
		V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF	-	5.3	11.4	1.0	13.0	1.0	14.5	ns
f _{max}	maximum	see Fig. 7								
	frequency	V_{CC} = 4.5 V to 5.5 V; C _L = 15 pF	100	160	-	80	-	80	-	MHz
		V_{CC} = 4.5 V to 5.5 V; C _L = 50 pF	80	140	-	65	-	65	-	MHz
t _W	pulse width	CP HIGH or LOW; $n\overline{S}D$, $n\overline{R}D$ LOW; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 7</u> and <u>Fig. 8</u>	5.0	-	-	5.0	-	5.0	-	ns
t _{su}	set-up time	nD to nCP; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 7</u>	5.0	-	-	5.0	-	5.0	-	ns
t _h	hold time	nD to nCP; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 7</u>		-	-	0	-	0	-	ns
t _{rec}	recovery time	nRD to nCP; V _{CC} = 4.5 V to 5.5 V; see <u>Fig. 8</u>	3.5	-	-	3.5	-	3.5	-	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz}; V_1 = \text{GND to } V_{CC}$ [3	3] -	16	-	-	-	-	-	pF

[1] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V and V_{CC} = 5.0 V).

[2] t_{pd} is the same as t_{PLH} and t_{PHL} . [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

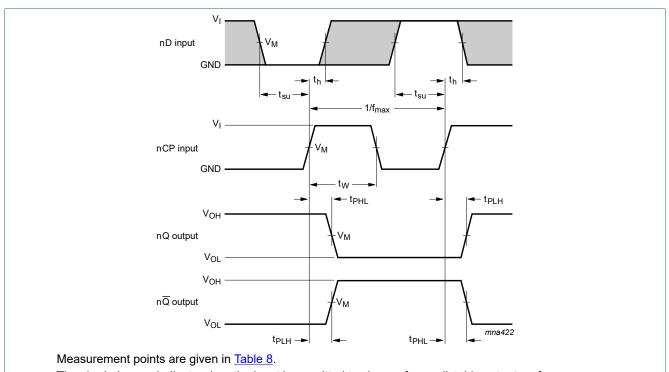
 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.



10.1. Waveforms

The shaded areas indicate when the input is permitted to change for predictable output performance. V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 7. Clock pulse width, maximum frequency, set-up times, hold times and input to output propagation delays

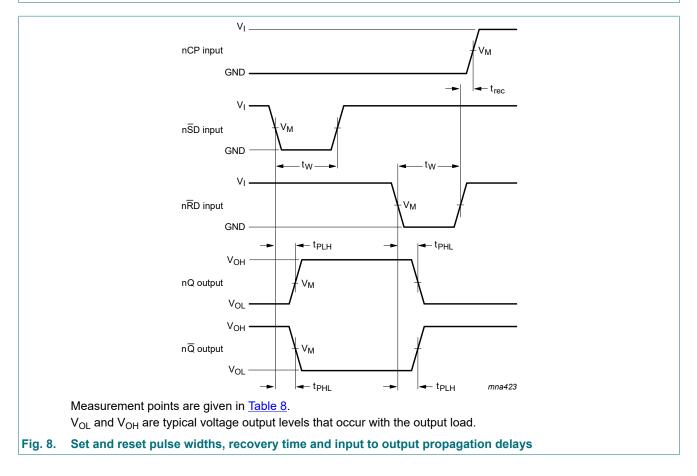
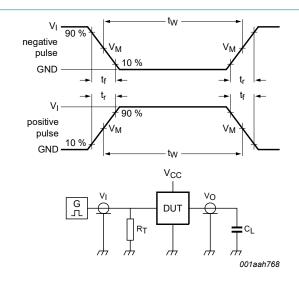


Table 8. Measurement points

Туре	Input	Output
	V _M	V _M
74AHC74-Q100	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74AHCT74-Q100	1.5 V	$0.5 \times V_{CC}$



For test data, see Table 9.

Definitions for test circuit:

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

Fig. 9. Test circuit for measuring switching times

Table 9. Test data

Туре	Input Lo		Load	Test
	VI	t _r , t _f	CL	
74AHC74-Q100	V _{CC}	≤ 3.0 ns	50 pF, 15 pF	t _{PLH} , t _{PHL}
74AHCT74-Q100	3.0 V	≤ 3.0 ns	50 pF, 15 pF	t _{PLH} , t _{PHL}

11. Package outline

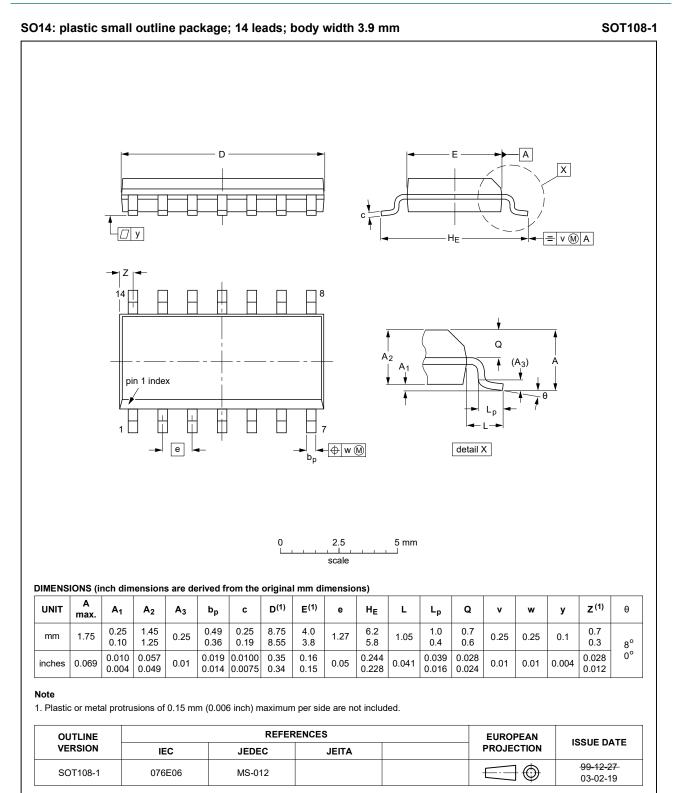


Fig. 10. Package outline SOT108-1 (SO14)

74AHC_AHCT74_Q100

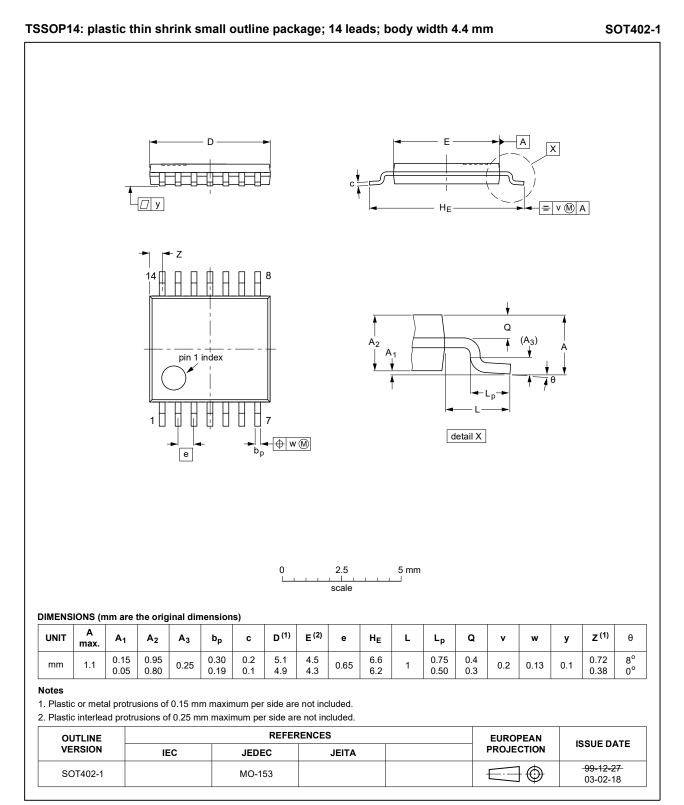


Fig. 11. Package outline SOT402-1 (TSSOP14)

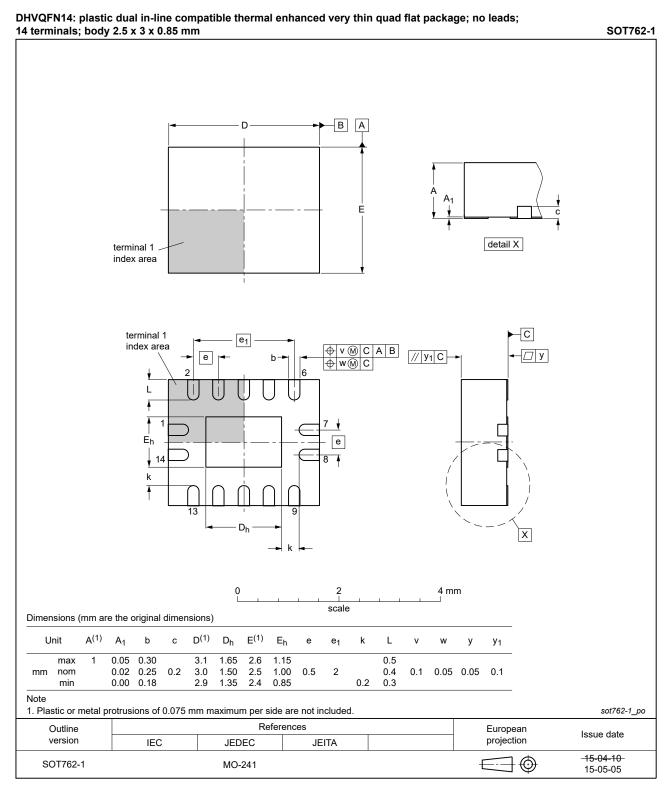


Fig. 12. Package outline SOT762-1 (DHVQFN14)

12. Abbreviations

Table 10. Abbreviation	ons
Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MIL	Military
MM	Machine Model

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AHC_AHCT74_Q100 v.3	20200422	Product data sheet	-	74AHC_AHCT74_Q100 v.2		
Modifications:	guidelines c Legal texts <u>Section 2</u> u <u>Table 4</u> : Der <u>Table 7</u> : mir	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. <u>Section 2</u> updated. <u>Table 4</u>: Derating values for P_{tot} total power dissipation updated. <u>Table 7</u>: minimum f_{max} values at 3.0 V to 3.6 V for 74AHC74 corrected (errata). <u>Fig. 12</u>: Package outline drawing SOT762-1 (DHVQFN14) updated. 				
74AHC_AHCT74_Q100 v.2	20150421	Product data sheet	-	74AHC_AHCT74_Q100 v.1		
Modifications:	• <u>Table 3</u> corrected (errata).					
74AHC_AHCT74_Q100 v.1	20130416	Product data sheet	-	-		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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